National Semiconductor

September 24, 2009

LM98722

3 Channel, 16-Bit, 45 MSPS Analog Front End with LVDS/CMOS Output, Integrated CCD/CIS Sensor Timing Generator and Spread Spectrum Clock Generation

General Description

The LM98722 is a fully integrated, high performance 16-Bit, 45 MSPS signal processing solution for digital color copiers, scanners, and other image processing applications. High-speed signal throughput is achieved with an innovative architecture utilizing Correlated Double Sampling (CDS), typically employed with CCD arrays, or Sample and Hold (S/H) inputs (for higher speed CCD or CMOS image sensors). The signal paths utilize 8 bit Programmable Gain Amplifiers (PGA), a +/-9-Bit offset correction DAC and independently controlled Digital Black Level correction loops for each input. The PGA and offset DAC are programmed independently allowing unique values of gain and offset for each of the three analog inputs. The signals are then routed to a 45MHz high performance analog-to-digital converter (ADC). The fully differential processing channel shows exceptional noise immunity, having a very low noise floor of -74dB. The 16-bit ADC has excellent dynamic performance making the LM98722 transparent in the image reproduction chain.

A very flexible integrated Spread Spectrum Clock Generation (SSCG) modulator is included to assist with EM compliance and reduce system costs.

Applications

- Multi-Function Peripherals
- High-speed Currency/Check Scanners
- Flatbed or Handheld Color Scanners
- High-speed Document Scanners

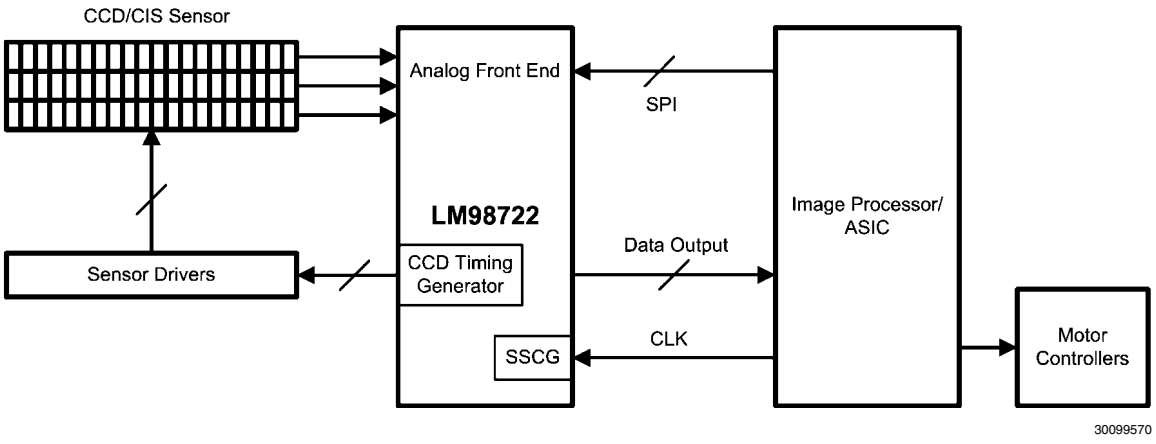
Features

- LVDS/CMOS Outputs
- LVDS/CMOS/Crystal Clock Source with PLL Multiplication
- Integrated Flexible Spread Spectrum Clock Generation
- CDS or S/H Processing for CCD or CIS sensors
- Independent Gain/Offset Correction for Each Channel
- Automatic per-Channel Gain and Offset Calibration
- Programmable Input Clamp Voltage
- Flexible CCD/CIS Sensor Timing Generator

Key Specifications

Maximum Input Level	1.2 or 2.4 Volt Modes (both with + or - polarity option)
ADC Resolution	16-Bit
ADC Sampling Rate	45 MSPS
INL	+18/-25 LSB (typ)
Channel Sampling Rate	22.5/22.5/15 MSPS
PGA Gain Steps	256 Steps
PGA Gain Range	0.64 to 8.3x
Analog DAC Resolution	+/-9 Bits
Analog DAC Range	+/-307mV or +/-614mV
Digital DAC Resolution	+/-6 Bits
Digital DAC Range	-2048 LSB to + 2016 LSB
SNR	-74dB (@0dB PGA Gain)
Power Dissipation	630mW (LVDS)
Operating Temp	0 to 70°C
Supply Voltage	3.3V Nominal (3.0V to 3.6V range)

System Block Diagram



LM98722 Overall Chip Block Diagram

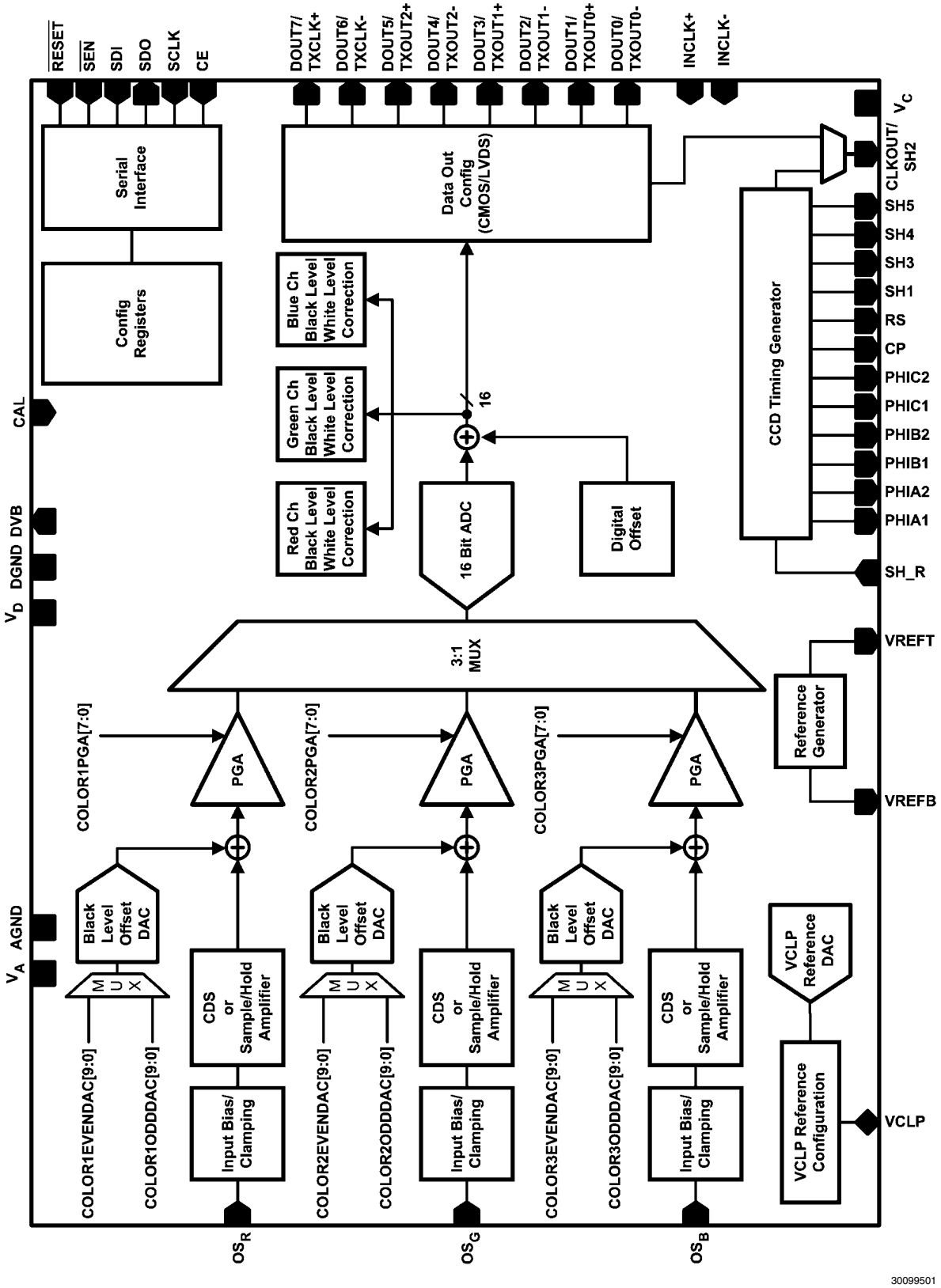


FIGURE 1. Chip Block Diagram

LM98722 Pin Out Diagram

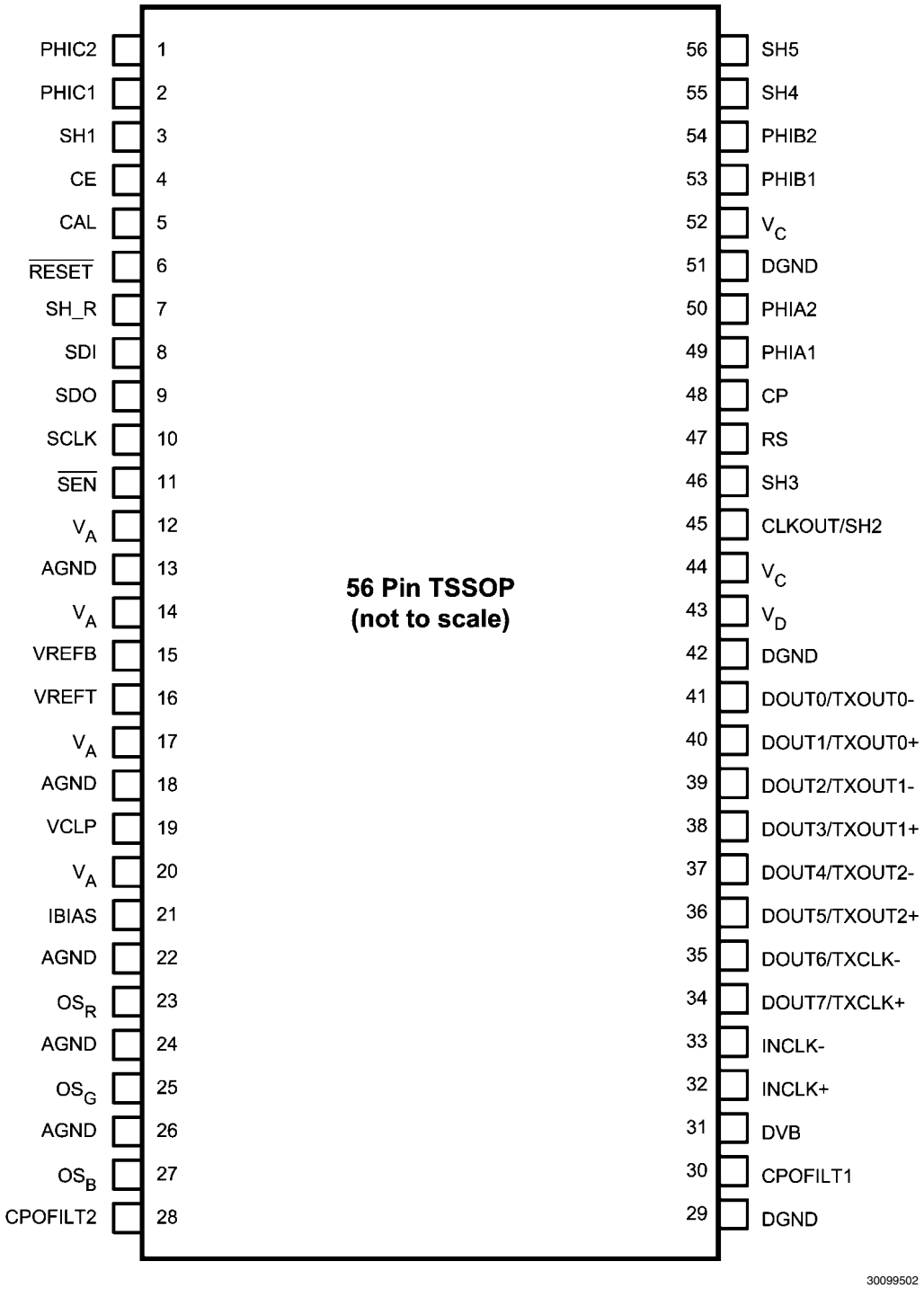


FIGURE 2. LM98722 Pin Out Diagram

Typical Application Diagram

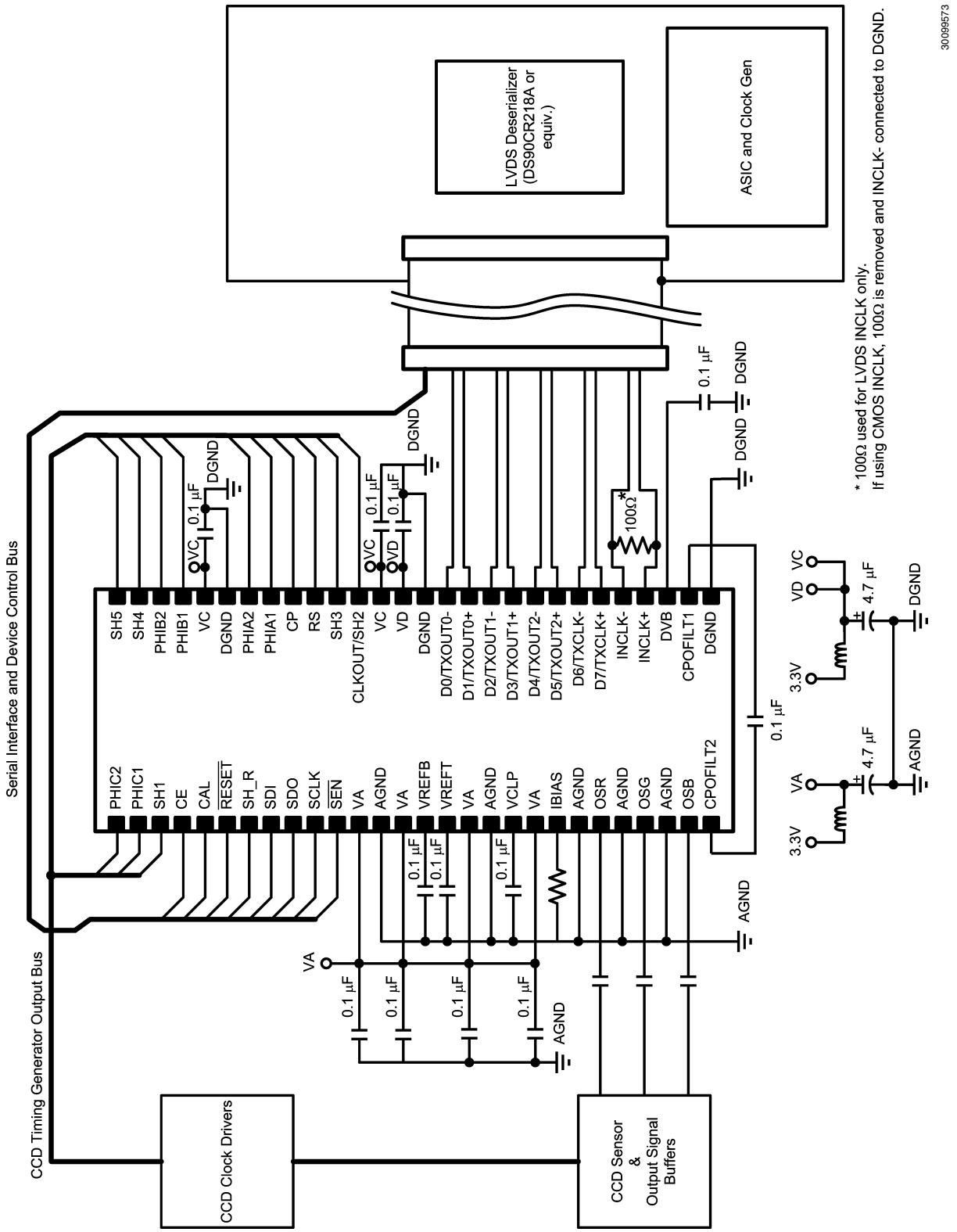


FIGURE 3. Typical Application Diagram

Pin Descriptions

Pin	Name	I/O	Typ	Res	Description
1	PHIC2	O	D	PU	Configurable high speed sensor timing output.
2	PHIC1	O	D	PD	Configurable high speed sensor timing output.
3	SH1	O	D	PU	Configurable low speed sensor timing output.
4	CE	I	D		Chip Serial Interface Address Setting Input
					CE Level / **Address**
					V_D / 01
					Float / 10
					DGND / 00
5	CAL	I	D	PD	Initiate calibration sequence. Leave unconnected or tie to DGND if unused.
6	$\overline{\text{RESET}}$	I	D	PU	Active-low master reset. NC when function not being used.
7	SH_R	I	D	PD	External request for an SH interval.
8	SDI	I	D	PD	Serial Interface Data Input.
9	SDO	O	D		Serial Interface Data Output.
10	SCLK	I	D	PD	Serial Interface shift register clock.
11	$\overline{\text{SEN}}$	I	D	PU	Active-low chip enable for the Serial Interface.
12	V_A		P		Analog power supply. Bypass voltage source with 4.7µF and pin with 0.1µF to AGND.
13	AGND		P		Analog ground return.
14	V_A		P		Analog power supply. Bypass voltage source with 4.7µF and pin with 0.1µF to AGND.
15	VREFB	O	A		Bottom of ADC reference. Bypass with a 0.1µF capacitor to ground.
16	VREFT	O	A		Top of ADC reference. Bypass with a 0.1µF capacitor to ground.
17	V_A		P		Analog power supply. Bypass voltage source with 4.7µF and pin with 0.1µF to AGND.
18	AGND		P		Analog ground return.
19	VCLP	IO	A		Input Clamp Voltage. Normally bypassed with a 0.1µF , and a 4.7µF capacitor to AGND. An external reference voltage may be applied to this pin.
20	V_A		P		Analog power supply. Bypass voltage source with 4.7µF and pin with 0.1µF to AGND.
21	IBIAS	O	A		Bias setting pin. Connect a 9.0 kOhm 1% resistor to AGND.
22	AGND		P		Analog ground return.
23	OS_R	I	A		Analog input signal. Typically sensor Red output AC-coupled thru a capacitor.
24	AGND		P		Analog ground return.
25	OS_G	I	A		Analog input signal. Typically sensor Green output AC-coupled thru a capacitor.
26	AGND		P		Analog ground return.
27	OS_B	I	A		Analog input signal. Typically sensor Blue output AC-coupled thru a capacitor.
28	CPOFILT2		A		Charge Pump Filter Capacitor. Bypass this supply pin with a 0.1µF capacitor to CPOFILT1.
29	DGND		P		Digital ground return.
30	CPOFILT1		A		Charge Pump Filter Capacitor. Bypass this supply pin with a 0.1µF capacitor to CPOFILT2.
31	DVB	O	D		Digital Core Voltage bypass. Not an input. Bypass with 0.1µF capacitor to DGND.
32	INCLK+	I	D		Clock Input. Non-Inverting input for LVDS clocks or CMOS clock input. CMOS clock is selected when pin 29 is held at DGND, otherwise clock is configured for LVDS operation.
33	INCLK-	I	D		Clock Input. Inverting input for LVDS clocks, connect to DGND for CMOS clock.
34	DOUT7/ TXCLK+	O	D		Bit 7 of the digital video output bus in CMOS Mode, LVDS Frame Clock+ in LVDS Mode.
35	DOUT6/ TXCLK-	O	D		Bit 6 of the digital video output bus in CMOS Mode, LVDS Frame Clock- in LVDS Mode.
36	DOUT5/ TXOUT2+	O	D		Bit 5 of the digital video output bus in CMOS Mode, LVDS Data Out2+ in LVDS Mode.

Pin	Name	I/O	Typ	Res	Description
37	DOUT4/ TXOUT2-	O	D		Bit 4 of the digital video output bus in CMOS Mode, LVDS Data Out2- in LVDS Mode.
38	DOUT3/ TXOUT1+	O	D		Bit 3 of the digital video output bus in CMOS Mode, LVDS Data Out1+ in LVDS Mode.
39	DOUT2/ TXOUT1-	O	D		Bit 2 of the digital video output bus in CMOS Mode, LVDS Data Out1- in LVDS Mode.
40	DOUT1/ TXOUT0+	O	D		Bit 1 of the digital video output bus in CMOS Mode, LVDS Data Out0+ in LVDS Mode.
41	DOUT0/ TXOUT0-	O	D		Bit 0 of the digital video output bus in CMOS Mode, LVDS Data Out0- in LVDS Mode.
42	DGND	O	D	PD	Configurable sensor control output.
43	V_D		P		Power supply for the digital circuits. Bypass this supply pin with 0.1µF capacitor. A single 4.7µF capacitor should be used between the supply and the VD, VR and VC pins.
44	V_C		P		Power supply for the sensor control outputs. Bypass this supply pin with 0.1µF capacitor.
45	CLKOUT/SH2	O	D		Output clock for registering output data when using CMOS outputs, or a configurable low speed sensor timing output.
46	SH3	O	D		Configurable low speed sensor timing output.
47	RS	O	D		Configurable high speed sensor timing output.
48	CP	O	D		Configurable high speed sensor timing output.
49	PHIA1	O	D		Configurable high speed sensor timing output.
50	PHIA2	O	D		Configurable high speed sensor timing output.
51	DGND		P		Digital ground return.
52	V_C		P		Power supply for the sensor control outputs. Bypass this supply pin with 0.1µF capacitor.
53	PHIB1	O	D		Configurable high speed sensor timing output.
54	PHIB2	O	D		Configurable high speed sensor timing output.
55	SH4	O	D		Configurable low speed sensor timing output.
56	SH5	O	D		Configurable low speed sensor timing output.

(I=Input), (O=Output), (IO=Bi-directional), (P=Power), (D=Digital), (A=Analog), (PU=Pull Up with an internal resistor), (PD=Pull Down with an internal resistor.).

Absolute Maximum Ratings (Note 1, Note 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage (VA,VR,VD,VC)	4.2V
Voltage on Any Input Pin (Not to exceed 4.2V)	−0.3V to (VA + 0.3V)
Voltage on Any Output Pin (execpt DVB and not to exceed 4.2V)	−0.3V to (VA + 0.3V)
DVB Output Pin Voltage	2.0V
Input Current at any pin other than Supply Pins (Note 3)	±25 mA
Package Input Current (except Supply Pins) (Note 3)	±50 mA
Maximum Junction Temperature (TA)	150°C
Thermal Resistance (θ_{JA})	<66°C/W
Package Dissipation at T_A = 25°C (Note 4)	>1.89W
ESD Rating (Note 5)	
Human Body Model	2500V
Machine Model	250V
Storage Temperature	−65°C to +150°C

Soldering process must comply with National Semiconductor's Reflow Temperature Profile specifications. Refer to www.national.com/packaging. (Note 6)

Operating Ratings (Note 1, Note 2)

Operating Temperature Range	0°C ≤ T_A ≤ +70°C
All Supply Voltage	+3.0V to +3.6V

Electrical Characteristics

The following specifications apply for VA = VD = VC = 3.3V, C_L = 10pF, and f_{INCLK} = 15MHz unless otherwise specified. **Boldface limits apply for $T_A = T_{MIN}$ to T_{MAX};** all other limits T_A = 25°C.

Symbol	Parameter	Conditions	Min (Note 9)	Typ (Note 8)	Max (Note 9)	Units
CMOS Digital Input DC Specifications (RESETb, SH_R, SCLK, SENb)						
V_{IH}	Logical "1" Input Voltage		2.0			V
V_{IL}	Logical "0" Input Voltage				0.8	V
V_{IHYST}	Logic Input Hysteresis			0.6		
I_{IH}	Logical "1" Input Current	V_{IH} = VD				
		$\overline{RESET}$,$\overline{SEN}$		100		nA
		SH_R, SCLK, SDI, CAL		65		µA
		CE		30		nA
I_{IL}	Logical "0" Input Current	V_{IL} = DGND				
		$\overline{RESETSEN}$		-65		µA
		SH_R, SCLK, SDI, CAL		-100		nA
		CE		-30		µA
CMOS Digital Output DC Specifications (SH1 to SH5, RS, CP, PHIA, PHIB, PHIC)						
V_{OH}	Logical "1" Output Voltage	I_{OUT} = -0.5mA	3.0			V
V_{OL}	Logical "0" Output Voltage	I_{OUT} = 1.6mA			0.21	V
I_{OS}	Output Short Circuit Current	V_{OUT} = DGND		18		mA
		V_{OUT}= VD		-25		
I_{OZ}	CMOS Output TRI-STATE Current	V_{OUT} = DGND		20		nA
		V_{OUT} = VD		-25		
CMOS Digital Output DC Specifications (CMOS Data Outputs)						
V_{OH}	Logical "1" Output Voltage	I_{OUT} = -0.5mA		2.3		V
V_{OL}	Logical "0" Output Voltage	I_{OUT} = 1.6mA		0.12		V
I_{OS}	Output Short Circuit Current	V_{OUT} = DGND		12		mA
		V_{OUT}= VD		-14		
I_{OZ}	CMOS Output TRI-STATE Current	V_{OUT} = DGND		20		nA
		V_{OUT} = VD		-25		

Symbol	Parameter	Conditions	Min (*Note 9*)	Typ (*Note 8*)	Max (*Note 9*)	Units
LVDS/CMOS Clock Receiver DC Specifications (INCLK+ and INCLK- Pins)						
V_{IHL}	Differential LVDS Clock High Threshold Voltage	R_L = 100Ω V_{CM} (LVDS Input Common Mode Voltage)= 1.25V			200	mV
V_{ILL}	Differential LVDS Clock Low Threshold Voltage		-200			mV
V_{IHC}	CMOS Clock High Threshold Voltage	INCLK- = DGND	2.0			V
V_{ILC}	CMOS Clock Low Threshold Voltage				0.8	V
I_{IHL}	CMOS Clock Input High Current			230	260	µA
I_{ILC}	CMOS Clock Input Low Current		-135	-120		µA
LVDS Output DC Specifications						
V_{OD}	Differential Output Voltage	R_L = 100Ω	280	390	490	mV
V_{OS}	LVDS Output Offset Voltage		1.08	1.20	1.33	V
I_{OS}	Output Short Circuit Current	V_{OUT} = 0V, R_L = 100Ω		8.5		mA
Power Supply Specifications						
IA	VA Analog Supply Current	LVDS Output Data Format		139	162	mA
		LVDS Output Data Format (Powerdown)		3.1	4.5	mA
		CMOS Output Data Format (40 MHz)		137	161	mA
ID	VD Digital Output Driver Supply Current	LVDS Output Data Format		50	65	mA
		LVDS Output Data Format (Powerdown)		5.5	8	mA
		CMOS Output Data Format (ATE Loading of CMOS Outputs > 50 pF) (40 MHz)		48	62	mA
IC	VC CCD Timing Generator Output Driver Supply Current	Typical sensor outputs: SH1-SH5, PHIA, PHIB, PHIC, RS, CP (ATE Loading of CMOS Outputs > 50pF)		1	4	mA
PWR	Average Power Dissipation	LVDS Output Data Format		630	736	mW
		LVDS Output Data Format (Powerdown)		28	32	mW
		CMOS Output Data Format (ATE Loading of CMOS Outputs > 50pF) (40 MHz)		600	740	mW
Input Sampling Circuit Specifications						
V_{IN}	Input Voltage Level	CDS Gain=1x, PGA Gain=1x CDS Gain=2x, PGA Gain= 1x		2.3 1.22		Vp-p

Symbol	Parameter	Conditions	Min (Note 9)	Typ (Note 8)	Max (Note 9)	Units
I_{IN_SH}	Sample and Hold Mode Input Leakage Current	Source Followers Off CDS Gain = 1x OS_X = VA (OS_X = AGND)	(-103)	19 (-95)	25	µA
		Source Followers Off CDS Gain = 2x OS_X = VA (OS_X = AGND)	(-152)	33 (-141)	50	µA
		Source Followers On CDS Gain = 2x OS_X = VA (OS_X = AGND)	(-250)	20 (-50)	250	nA
C_{SH}	Sample/Hold Mode Equivalent Input Capacitance	CDS Gain = 1x		2.5		pF
		CDS Gain = 2x		4		pF
I_{IN_CDS}	CDS Mode Input Leakage Current	Source Followers Off OS_X = VA (OS_X = AGND)	(-250)	10 (-50)	250	nA
R_{CLPIN}	CLPIN Switch Resistance (OS_X to VCLP Node)			16	55	Ω
VCLP Reference Circuit Specifications						
V_{VCLP}	VCLP Voltage 000	VCLP Voltage Setting = 000		0.85VA		V
	VCLP Voltage 001	VCLP Voltage Setting = 001		0.9VA		V
	VCLP Voltage 010	VCLP Voltage Setting = 010		0.95VA		V
	VCLP Voltage 011	VCLP Voltage Setting = 011		0.6VA		V
	VCLP Voltage 100	VCLP Voltage Setting = 100		0.55VA		V
	VCLP Voltage 101	VCLP Voltage Setting = 101		0.4VA		V
	VCLP Voltage 110	VCLP Voltage Setting = 110		0.35VA		V
	VCLP Voltage 111	VCLP Voltage Setting = 111		0.15VA		V
I_{SC}	VCLP DAC Short Circuit Output Current	0001 xxxxb VCLP Config. Register =		30		mA
Black Level Offset DAC Specifications						
	Resolution			10		Bits
	Monotonicity		Guaranteed by characterization			
	Offset Adjustment Range Referred to AFE Input	CDS Gain = 1x Minimum DAC Code = 0x000 Maximum DAC Code = 0x3FF		-614 614		mV
		CDS Gain = 2x Minimum DAC Code = 0x000 Maximum DAC Code = 0x3FF		-307 307		mV
	Offset Adjustment Range Referred to AFE Output	Minimum DAC Code = 0x000 Maximum DAC Code = 0x3FF	-17500 +16130		-16130 +17500	LSB
	DAC LSB Step Size	CDS Gain = 1x Referred to AFE Output		1.2 (32)		mV (LSB)
DNL	Differential Non-Linearity		-0.85	+0.74/ -0.37	+2.4	LSB
INL	Integral Non-Linearity		-2.5	+0.72/ -0.56	+2.5	LSB
PGA Specifications						
	Gain Resolution			8		Bits
	Monotonicity		Guaranteed by characterization			
	Maximum Gain	CDS Gain = 1x	7.7	8.3	8.8	V/V
		CDS Gain = 1x	17.7	18.4	18.9	dB

Symbol	Parameter	Conditions	Min (*Note 9*)	Typ (*Note 8*)	Max (*Note 9*)	Units
	Minimum Gain	CDS Gain = 1x	0.58	0.64	0.70	V/V
		CDS Gain = 1x	-4.7	-4.2	-3.5	dB
	PGA Function	Gain (V/V) = (180/(277-PGA Code)) Gain (dB) = 20LOG10(180/(277-PGA Code))				
	Channel Matching	Minimum PGA Gain Maximum PGA Gain		3 12.7		%
ADC Specifications						
V_{REFT}	Top of Reference			2.07		V
V_{REFB}	Bottom of Reference			0.89		V
V_{REFT} - V_{REFB}	Differential Reference Voltage		1.06	1.18	1.30	V
	Overrange Output Code			65535		
	Underrange Output Code			0		
Digital Offset "DAC" Specifications						
	Resolution			7		Bits
	Digital Offset DAC LSB Step Size	Referred to AFE Output		32		LSB
	Offset Adjustment Range Referred to AFE Output	Min DAC Code =7b0000000 Mid DAC Code =7b1000000 Max DAC Code = 7b1111111		-2048 0 +2016		LSB
Full Channel Performance Specifications						
DNL	Differential Non-Linearity	(*Note 10*)	-0.999	+0.8/-0.7	2.5	LSB
INL	Integral Non-Linearity	(*Note 10*)	-75	+18/-25	75	LSB
SNR	Total Output Noise	Minimum PGA Gain (*Note 10*)		-76		dB
				10	26	LSB RMS
		Maximum PGA Gain (*Note 10*)		-56		dB
				96		LSB RMS
	Channel to Channel Crosstalk	Mode 3		26		LSB
		Mode 2		17		

AC Timing Specifications

The following specifications apply for VA = VD = VC = 3.3V, C_L = 10pF, and f_{INCLK} = 15MHz unless otherwise specified. **Boldface limits apply for $T_A = T_{MIN}$ to T_{MAX};** all other limits T_A = 25°C.

Symbol	Parameter	Conditions	Min (*Note 9*)	Typ (*Note 8*)	Max (*Note 9*)	Units
Input Clock Timing Specifications						
f_{INCLK}	Input Clock Frequency	INCLK = PIXCLK (Pixel Rate Clock)	0.66 1 1		15 (Mode 3) 22.5 (Mode 2) 22.5 (Mode 1)	MHz
		INCLK = ADCCLK (ADC Rate Clock)	2		45 (Mode 3) 45 (Mode 2) 22.5 (Mode 1)	MHz
T_{dc}	Input Clock Duty Cycle		40/60	50/50	60/40	%
Full Channel Latency Specifications						
t_{LAT3}	3 Channel Mode Pipeline Delay	PIXPHASE0		24		T_{ADC}
		PIXPHASE1		23 1/2		
		PIXPHASE2		23		
		PIXPHASE3		22 1/2		
t_{LAT2}	2 Channel Mode Pipeline Delay	PIXPHASE0		21		T_{ADC}
		PIXPHASE1		20 1/2		
		PIXPHASE2		20		
		PIXPHASE3		19 1/2		
t_{LAT1}	1 Channel Mode Pipeline Delay	PIXPHASE0		19		T_{ADC}
		PIXPHASE1		18 1/2		
		PIXPHASE2		18		
		PIXPHASE3		17 1/2		
SH_R Timing Specifications						
t_{SHR_S}	SH_R Setup Time			2		ns
t_{SHR_H}	SH_R Hold Time			2		ns
LVDS Output Timing Specifications						
TX_{pp0}	TXCLK to Pulse Position 0	LVDS Output Specifications not tested in production. Min/Max guaranteed by design, characterization and statistical analysis.	-0.46	0	0.46	ns
TX_{pp1}	TXCLK to Pulse Position 1		2.71	3.17	3.63	ns
TX_{pp2}	TXCLK to Pulse Position 2		5.89	6.35	6.81	ns
TX_{pp3}	TXCLK to Pulse Position 3		9.06	9.52	9.98	ns
TX_{pp4}	TXCLK to Pulse Position 4		12.24	12.70	13.16	ns
TX_{pp5}	TXCLK to Pulse Position 5		15.41	15.87	16.33	ns
TX_{pp6}	TXCLK to Pulse Position 6		18.59	19.05	19.51	ns
CMOS Output Timing Specifications						
t_{CRDO}	CLKOUT Rising Edge to CMOS Output Data Transition	f_{INCLK} = 40MHz INCLK = ADCCLK (ADC Rate Clock)	2	6	9	ns
Serial Interface Timing Specifications						

Symbol	Parameter	Conditions	Min (*Note 9*)	Typ (*Note 8*)	Max (*Note 9*)	Units
f_{SCLK}	Input Clock Frequency	f_{SCLK} <= f_{INCLK} INCLK = PIXCLK (Pixel Rate Clock) Mode 3/2/1			15/22.5/22.5	MHz
		f_{SCLK} <= f_{INCLK} INCLK = ADCCLK (ADC Rate Clock) Mode 3/2/1			45/45/22.5	MHz
	SCLK Duty Cycle			50/50		ns
t_{IH}	Input Hold Time		1.5			ns
t_{IS}	Input Setup Time		2.5			ns
t_{SENSC}	SCLK Start Time After $\overline{SEN}$ Low		1.5			ns
t_{SCSEN}	$\overline{SEN}$ High after last SCLK Rising Edge		2.5			ns
t_{SENW}	$\overline{SEN}$ Pulse Width	INCLK present INCLK stopped (*Note 11*, *Note 12*)	6 50			T_{INCLK} ns
t_{OD}	Output Delay Time			11	14	ns
t_{HZ}	Data Output to High Z				0.5	T_{SCLK}

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions. Operation of the device beyond the Operating Ratings is not recommended.

Note 2: All voltages are measured with respect to AGND = DGND = 0V, unless otherwise specified.

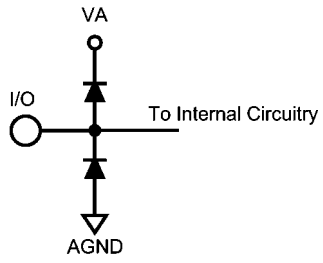
Note 3: When the input voltage (V_{IN}) at any pin exceeds the power supplies (V_{IN} < GND or V_{IN} > V_A or V_D), the current at that pin should be limited to 25 mA. The 50 mA maximum package input current rating limits the number of pins that can simultaneously safely exceed the power supplies with an input current of 25 mA to two.

Note 4: The maximum power dissipation must be derated at elevated temperatures and is dictated by T_{JMAX}, θ_{JA} and the ambient temperature, T_A. The maximum allowable power dissipation at any temperature is $P_D = (T_{JMAX} - T_A)/\theta_{JA}$. The values for maximum power dissipation listed above will be reached only when the device is operated in a severe fault condition (e.g. when input or output pins are driven beyond the power supply voltages, or the power supply polarity is reversed). Such conditions should always be avoided.

Note 5: Human body model is 100 pF capacitor discharged through a 1.5 kΩ resistor. Machine model is 220 pF discharged through 0Ω.

Note 6: Reflow temperature profiles are different for lead-free and non-lead-free packages.

Note 7: The analog inputs are protected as shown below. Input voltage magnitudes beyond the supply rails will not damage the device, provided the current is limited per note 3. However, input errors will be generated If the input goes above VA and below AGND.



30099571

Note 8: Typical figures are at T_A = 25°C, and represent most likely parametric norms at the time of product characterization. The typical specifications are not guaranteed.

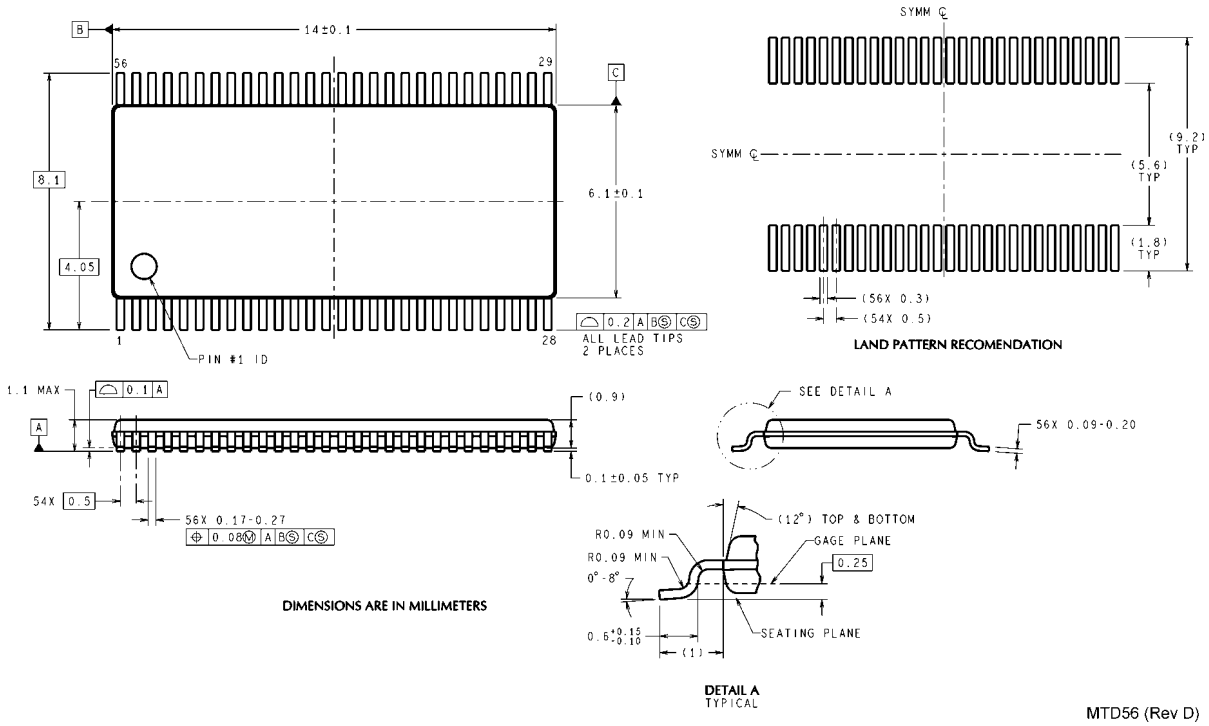
Note 9: Test limis are guaranteed to National's AOQL (Average Outgoing Quality Level).

Note 10: This parameter guaranteed by design and characterization.

Note 11: If the input INCLK is divided down to a lower internal clock rate via the PLL, the parameter t_{SENW} will be increased by the same factor.

Note 12: When the Spread Spectrum Clock Generation feature is enabled, t_{SENW} should be increased by 1.

Physical Dimensions inches (millimeters) unless otherwise noted



MTD56 (Rev D)

56-Lead TSSOP
NS Package Number MTD56

Notes

For more National Semiconductor product information and proven design tools, visit the following Web sites at:

Products		Design Support	
Amplifiers	www.national.com/amplifiers	WEBENCH® Tools	www.national.com/webench
Audio	www.national.com/audio	App Notes	www.national.com/appnotes
Clock and Timing	www.national.com/timing	Reference Designs	www.national.com/refdesigns
Data Converters	www.national.com/adc	Samples	www.national.com/samples
Interface	www.national.com/interface	Eval Boards	www.national.com/evalboards
LVDS	www.national.com/lvds	Packaging	www.national.com/packaging
Power Management	www.national.com/power	Green Compliance	www.national.com/quality/green
Switching Regulators	www.national.com/switchers	Distributors	www.national.com/contacts
LDOs	www.national.com/ldo	Quality and Reliability	www.national.com/quality
LED Lighting	www.national.com/led	Feedback/Support	www.national.com/feedback
Voltage Reference	www.national.com/vref	Design Made Easy	www.national.com/easy
PowerWise® Solutions	www.national.com/powerwise	Solutions	www.national.com/solutions
Serial Digital Interface (SDI)	www.national.com/sdi	Mil/Aero	www.national.com/milaero
Temperature Sensors	www.national.com/tempsensors	SolarMagic™	www.national.com/solarmagic
Wireless (PLL/VCO)	www.national.com/wireless	PowerWise® Design University	www.national.com/training

For the most current product information visit us at www.national.com

National Semiconductor Americas Technical Support Center
Email: support@nsc.com
Tel: 1-800-272-9959

National Semiconductor Europe Technical Support Center
Email: europe.support@nsc.com

National Semiconductor Asia Pacific Technical Support Center
Email: ap.support@nsc.com

National Semiconductor Japan Technical Support Center
Email: jpn.feedback@nsc.com